

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S1	56	(KNUDSEN near2 CARL).in.	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/11/24 12:32
S2	371227	(Magnet\$6 Magnetoresistive MRAM MTJ MJT) with (memory cell storage)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/24 13:04
S3	1680	(Magnet\$6 Magnetoresistive MRAM MTJ MJT) with (memory cell storage) with (tamper \$5 damag\$5 corrupt\$5)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/24 13:14
S4	17	((Magnet\$6 Magnetoresistive MRAM MTJ MJT) with (memory cell storage) with (tamper \$5 damag\$5 corrupt\$5)) same key	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/24 13:15
S5	1032	((Magnet\$6 Magnetoresistive MRAM MTJ MJT) near5 (memory cell storage) with (tamper \$5 damag\$5 corrupt\$5))	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/24 13:19
S6	118	(Magnet\$6 Magnetoresistive MRAM MTJ MJT) near5 (memory cell storage) with (tamper \$5 damag\$5 corrupt\$5) with (state value logic one zero binary S1 "0" sense sensing)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/24 13:20
S7	406	713/194 and(Magnet\$6 Magnetoresistive MRAM MTJ MJT)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/24 16:34

S8	250	713/194 and(Magnet\$6 Magnetoresistive MRAM MTJ MJT) near5 (memory cell storage register)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/24 16:35
S9	45	326/8 and(Magnet\$6 Magnetoresistive MRAM MTJ MJT)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/11/24 18:49
S10	10	magnetic adj resistive adj (ROM read)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/24 19:01
S11	7747	(Magnet adj junction Magnetoresistive MROM MTJ MJT) near5 (memory cell storage register chip)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/24 19:15
S12	39	(Magnet adj junction Magnetoresistive MROM MTJ MJT) near5 (memory cell storage register chip) with (tamper\$5 damag\$5 corrupt\$5)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/24 19:16
S13	13	("20010033012" or ("6404674") or ("20010005011") or ("6784796") or ("20080088996") or ("20010030839") or ("5675319") or ("5233505") or ("4860351") or ("5117457") or ("4401944") or ("6462979") or ("20060092020")).PN.	US_PGPUB; USPAT; USOCR	OR	OFF	2008/11/25 10:19
S14	31	("4053829").PN. OR ("4401944").URPN.	US_PGPUB; USPAT; USOCR	OR	OFF	2008/11/25 11:13

S15	67	("3108257" "3366939" "3451041" "3496554" "3666967" "3670837" "3725671" "3763795" "3825920" "3882323" "3882324" "3943503" "4110738" "4168396" "4179691" "4205307" "4225859" "4236463" "4352097" "4393479" "4459583" "4471163" "4512000" "4514720" "4543565" "4575621" "4593384" "4691350" "4734883" "4783801"). PN. OR ("4860351"). URPN.	US_PGPUB; USPAT; USOCR	OR	OFF	2008/11/25 11:20
S16	24	("4593384" "4783801" "4860351" "4933898" "5053992" "5060261" "5117457" "5159629" "5177352" "5353350" "5539828" "5790670" "6233339" "6264108" "6276609" "6396400" "6501390"). PN. OR ("7005733"). URPN.	US_PGPUB; USPAT; USOCR	OR	OFF	2008/11/25 12:07
S17	2	(("4817140") or ("5117457")). PN.	US_PGPUB; USPAT; USOCR	OR	OFF	2008/11/25 12:20
S18	32364	(Magnet\$6 Magnetoresistive MRAM MTJ MJT) with (bit)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/25 12:28
S19	239	(Magnet\$6 Magnetoresistive MRAM MTJ MJT) with (bit) with (tamper\$5 damag\$5 corrupt\$5 alarm\$5)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/25 12:30
S20	59591	(Magnet\$6 Magnetoresistive MRAM MTJ MJT) with (code coded coding)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/25 12:59
S21	1308	(Magnet\$6 Magnetoresistive MRAM MTJ MJT) with (code coded coding) with (tamper\$5 damag\$5 corrupt\$5 alarm\$5 eras\$5)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/25 13:02

S22	762	(Magnet\$6 Magnetoresistive MRAM MTJ MJT) with (code coded coding) with (tamper\$5 damag\$5 corrupt\$5 alarm\$5 eras\$5) same (memory cell storage register chip bit)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/25 13:05
S23	1451	(Magnet\$6 Magnetoresistive MRAM MTJ MJT) with (code coded coding) with (tamper\$5 damag\$5 corrupt\$5 alarm\$5 eras\$5 detect\$5) with (package module housing chip encapsulat\$5 circuit circuitry)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/25 13:09
S24	508	((Magnet\$6 Magnetoresistive MRAM MTJ MJT) near5 (code coded coding)) with (tamper\$5 damag\$5 corrupt\$5 alarm\$5 eras\$5 detect\$5) with (package module housing chip encapsulat\$5 circuit circuitry)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/25 13:10
S25	99308	(Magnet\$6 Magnetoresistive MRAM MTJ MJT) near5 (proximity orientation distance)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/25 14:43
S26	56	(KNUDSEN near2 CARL). in.	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/11/25 14:44
S27	27860	(Magnet\$6 Magnetoresistive MRAM MTJ MJT) near5 (proximity orientation distance) with (code coded coding state value logic one zero binary S26 "0" sense sensing bit)	US_PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/25 14:44

S28	2092	((Magnet\$6 Magnetoresistive MRAM MTJ MJT) near5 (proximity orientation distance)) with (code coded coding state value logic one zero binary S26 "0" sense sensing bit) with (memory cell storage register chip)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/25 14:45
S29	175	((Magnet\$6 Magnetoresistive MRAM MTJ MJT) near5 (proximity orientation distance)) with (code coded coding state value logic one zero binary S26 "0" sense sensing bit) with (memory cell storage register chip) and (key encrypt\$5 decrypt\$5)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/11/25 14:46
S30	1	("7005733").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/11/25 18:00
S31	19	"6477335" "3599132"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2008/11/25 18:33
S32	17	("4555696" "4929928" "5305390" "5317309" "5587703" "5640002" "5973732" "5995015" "6098048" "6104333" "6123259").PN. OR ("6563423").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2008/11/25 18:42
S33	204	726/34	US-PGPUB; USPAT; USOCR	OR	OFF	2008/11/25 18:44
S34	78	726/34 and (Magnet\$6 Magnetoresistive MRAM MTJ MJT)	US-PGPUB; USPAT; USOCR	OR	OFF	2008/11/25 18:45

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